NSN 5962-01-351-9513

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Overall Height: 0.400 inches Body Length: 1.280 inches Body Width:



View Online at https://aerobasegroup.com/nsn/5962-01-351-9513

	Between 0.220 inches and 0.310 inches
E	Body Height:
Е	Between 0.140 inches and 0.185 inches
N	Maximum Power Dissipation Rating:
1	.2 watts
(Operating Tempurature Range:
-	55.0/+125.0 degrees celsius
5	Storage Tempurature Range:
-	65.0/+150.0 degrees celsius
E	End Application:
5	Satellite communications terminal an/usc-3 (v) 1
F	Features Provided:
H	Hermetically sealed and burn in and monolithic and programmed
I	nclosure Material:
(Ceramic
I	nclosure Configuration:
	Dual-in-line
(Output Logic Form:
7	Fransistor-transistor logic
I	nput Circuit Pattern:
2	20 input
(Case Outline Source And Designator:
	D-9 mil-m-38510
(Current Rating Per Characteristic:
2	210.00 milliamperes reverse current, dc absolute
7	Ferminal Surface Treatment:
5	Solder
F	Product Name:
F	And-or invert gate array
١	/oltage Rating And Type Per Characteristic:
-	0.5 volts power source and 7.0 volts power source
1	Fime Rating Per Chacteristic:
2	25.00 nanoseconds delay
Ν	Memory Device Type:
F	Pal
7	Test Data Document:
ç	96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type Ar	nd Quantity:
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24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0